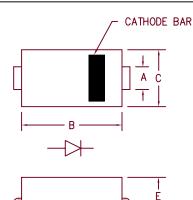
## 1 Amp Schottky Rectifier HSM180J — HSM1100J



Dim. Inches			Millimeter		
	Minimum	Maximum	Minimum	Maximum Notes	
A	.073	.087	1.85	2.21	
B	.160	.180	4.06	4.57	
C	.130	.155	3.30	3.94	
D	.205	.220	5.21	5.59	
E	.075	.130	1.91	3.30	
F	.030	.060	.760	1.52	

## DO-214BA Package

Microsemi Catalog Number	Industry Part Number	Working Peak Reverse Voltage	Repetitive Peak Reverse Voltage
HSM180J HSM190J	SK18 MBRS190TR MBRS190T3	80V 90V	80V 90V
HSM1100J	10BQ100 10MQ100N MBRS1100T3 SK110	100V	100V

- Uderwriters Laboratory Flammability Class 94V-0
- Schottky Barrier Rectifier
- Guard Ring Protection
- 175°C Junction Temperature
- Surface mount package

#### Electrical Characteristics

Average forward current
Maximum surge current
Max peak forward voltage
Max peak forward voltage
Max peak reverse current
Typical junction capacitance

IF(AV) 1.0 Amps IFSM 40 Amps VFM .57 Volts VFM .84 Volts IRM 100 µA CJ 45pF TL = 140°C, Square wave, ROJL = 15°C/W 8.3ms, half sine,  $^{T}J$  = 175°C  $^{I}FM$  = 0.1A:  $^{T}J$  = 25°C  $^{*}I$  FM = 1.0A:  $^{T}J$  = 25°C  $^{*}V$  RRM,  $^{T}J$  = 25°C  $^{V}R$  = 5.0V,  $^{T}J$  = 25°C

\*Pulse test: Pulse width 300 jusec, Duty cycle 2%

#### Thermal and Mechanical Characteristics

Storage temperature range Operating junction temp range Maximum thermal resistance Weight T<sub>STG</sub> T<sub>J</sub> R<del>O</del>JL

-55°C to 175°C -55°C to 175°C 15°C/W junction to lead .0047 ounces (.013 grams) typical

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05-15-07 Rev. 5

# HSM180J - HSM1100J

Figure 1 Typical Forward Characteristics

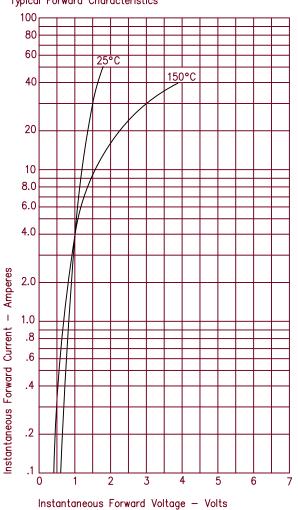


Figure 2

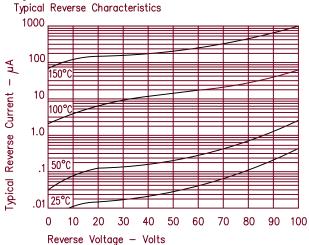
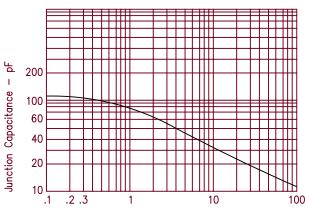
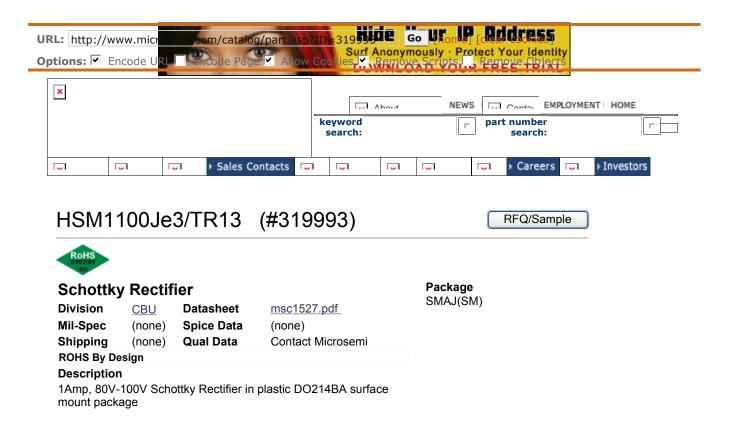


Figure 3
Typical Junction Capacitance



Reverse Voltage - Volts



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